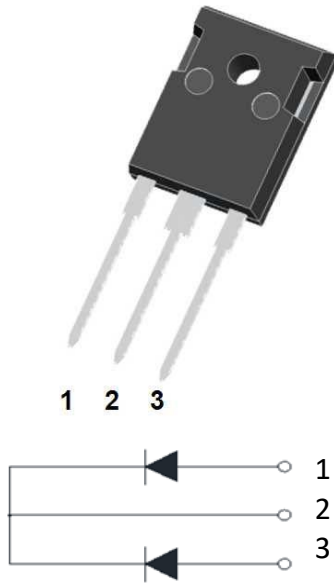


## Ultra-Fast Recovery Diodes 15A\*2 FRED



### Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

### Typical Applications

- Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### Mechanical Data

- **Package:** TO-247AB  
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

### ■Maximum Ratings (T<sub>j</sub>=25°C Unless otherwise specified)

| PARAMETER                                                                                   | SYMBOL           | UNIT             | MUR3060PT  |
|---------------------------------------------------------------------------------------------|------------------|------------------|------------|
| Device marking code                                                                         |                  |                  | MUR3060PT  |
| Repetitive Peak Reverse Voltage                                                             | V <sub>RRM</sub> | V                | 600        |
| Average Rectified Output Current<br>@60Hz sine wave, R-load, T <sub>c</sub> (FIG.1)         | I <sub>O</sub>   | A                | 30         |
| Surge(Non-repetitive)Forward Current<br>@60Hz half sine-wave, 1 cycle, T <sub>j</sub> =25°C | I <sub>FSM</sub> | A                | 150        |
| Current Squared Time<br>@1ms≤t≤8.3ms T <sub>j</sub> =25°C,                                  | I <sup>2</sup> t | A <sup>2</sup> s | 93         |
| Single Pulse Avalanche Energy @ T <sub>p</sub> =40uS,<br>T <sub>j</sub> =25°C,L=15mH        | EAS              | mJ               | 140        |
| Storage Temperature                                                                         | T <sub>stg</sub> | °C               | -55 ~ +175 |
| Junction Temperature                                                                        | T <sub>j</sub>   | °C               | -55 ~ +175 |
| Typical Junction capacitance @4V,1MHz                                                       | C <sub>j</sub>   | pF               | 98         |



# MUR3060PT

## ■Electrical Characteristics (T<sub>j</sub>=25°C Unless otherwise specified)

| PARAMETER                                                 | SYMBOL            | UNIT | TEST CONDITIONS                                                                         | Min | Typ  | Max |
|-----------------------------------------------------------|-------------------|------|-----------------------------------------------------------------------------------------|-----|------|-----|
| Instantaneous forward voltage drop per diode              | V <sub>FM</sub>   | V    | I <sub>FM</sub> =15.0A @ T <sub>j</sub> =25°C                                           | -   | 1.45 | 1.6 |
|                                                           |                   |      | I <sub>FM</sub> =15.0A @ T <sub>j</sub> =150°C                                          | -   | 1.25 | 1.4 |
| DC reverse current at rated DC blocking voltage per diode | I <sub>RRM1</sub> | uA   | V <sub>RM</sub> =V <sub>RRM</sub><br>T <sub>j</sub> =25°C                               | -   | -    | 5.0 |
|                                                           | I <sub>RRM2</sub> |      | V <sub>RM</sub> =V <sub>RRM</sub><br>T <sub>j</sub> =150°C                              | -   | 30   | 200 |
| Reverse Recovery Time                                     | T <sub>RR</sub>   | ns   | I <sub>F</sub> =0.5A I <sub>RM</sub> =1A I <sub>RR</sub> =0.25A<br>T <sub>j</sub> =25°C | -   | 26   | 35  |
|                                                           |                   |      | T <sub>j</sub> =25°C                                                                    |     | 115  |     |
|                                                           |                   |      | T <sub>j</sub> =125°C                                                                   |     | 200  |     |
| Peak recovery current                                     | I <sub>RRM</sub>  | A    | T <sub>j</sub> =25°C                                                                    | -   | 5.0  | -   |
|                                                           |                   |      | T <sub>j</sub> =125°C                                                                   | -   | 10.5 | -   |
| Reverse recovery charge                                   | Q <sub>rr</sub>   | nC   | T <sub>j</sub> =25°C                                                                    | -   | 285  | -   |
|                                                           |                   |      | T <sub>j</sub> =125°C                                                                   | -   | 1000 | -   |

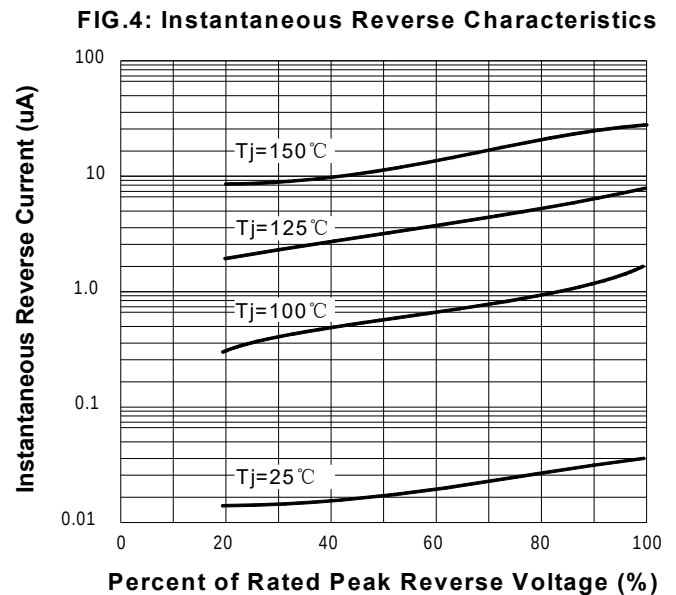
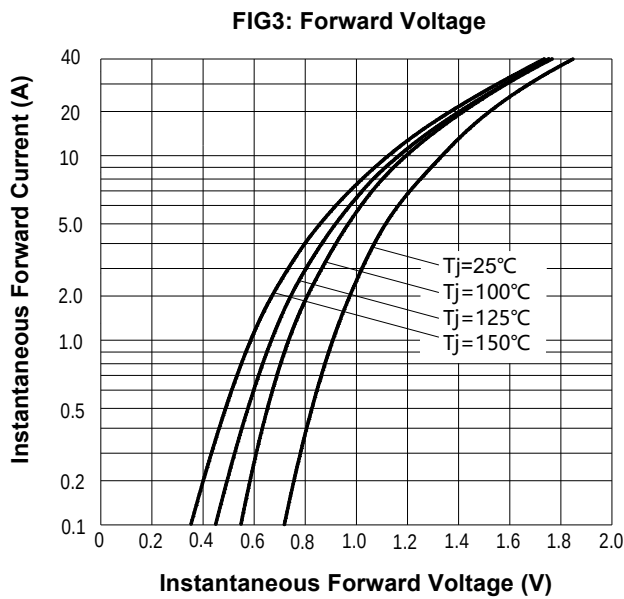
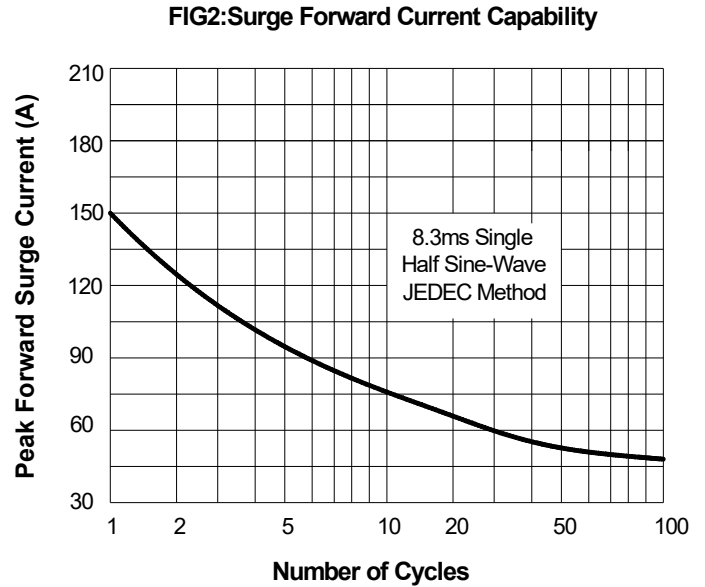
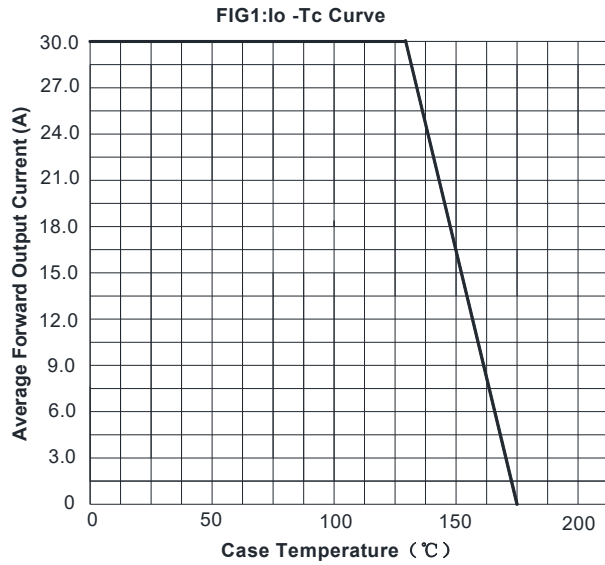
## ■Thermal Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

| PARAMETER          |                           | SYMBOL            | UNIT | MUR3060PT |
|--------------------|---------------------------|-------------------|------|-----------|
| Thermal Resistance | Between junction and case | R <sub>θJ-C</sub> | °CW  | 1.0       |
|                    | Between junction and Air  | R <sub>θJ-A</sub> | °CW  | 50        |

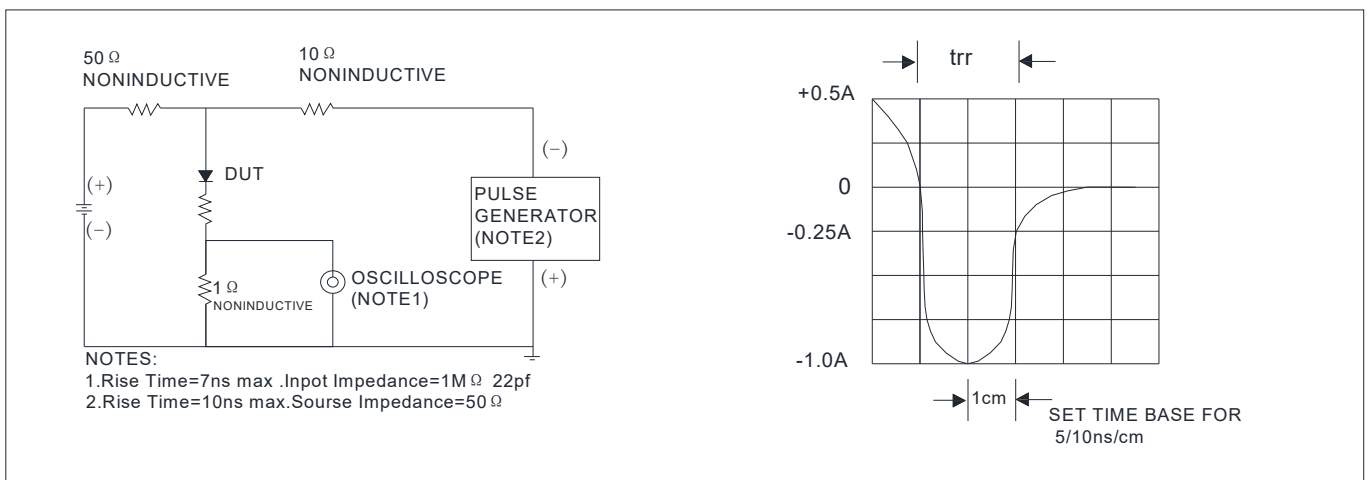


# MUR3060PT

## ■ Characteristics(Typical)



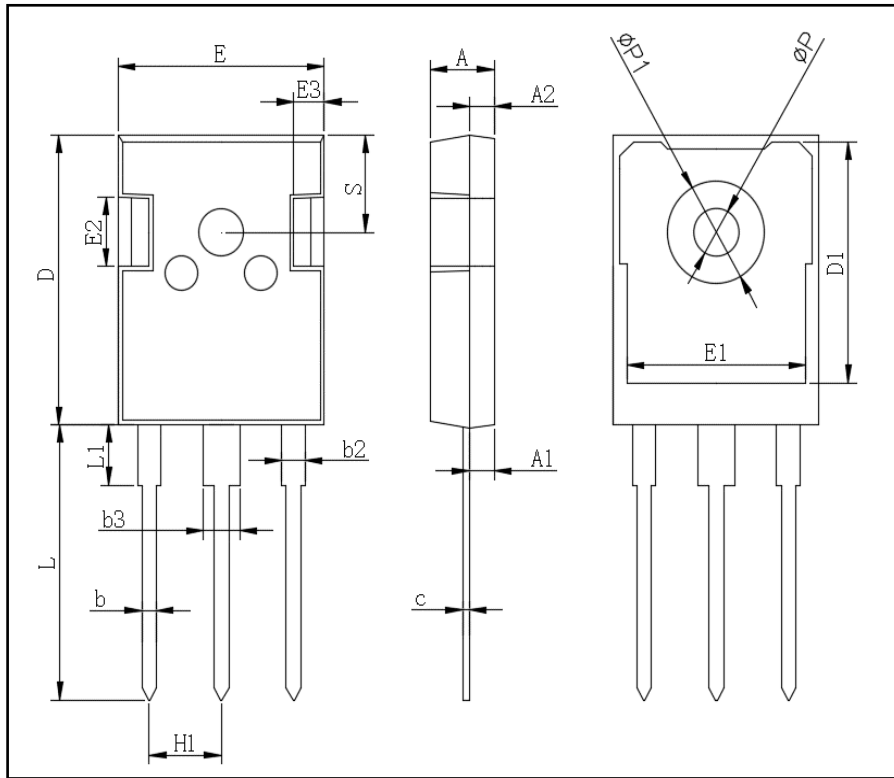
**FIG.5: Diagram of circuit and Testing wave form of reverse recovery time**





## MUR3060PT

### ■ Outline Dimensions



| TO-247AB |         |       |
|----------|---------|-------|
| Dim      | Min     | Max   |
| A        | 4.80    | 5.20  |
| A1       | 2.21    | 2.61  |
| A2       | 1.85    | 2.15  |
| b        | 1.0     | 1.4   |
| b2       | 1.91    | 2.21  |
| C        | 0.5     | 0.7   |
| D        | 20.70   | 21.30 |
| D1       | 16.25   | 16.85 |
| E        | 15.50   | 16.10 |
| E1       | 13.0    | 13.6  |
| E2       | 4.80    | 5.20  |
| E3       | 2.30    | 2.70  |
| L        | 19.62   | 20.22 |
| L1       | -       | 4.30  |
| ΦP       | 3.40    | 3.80  |
| ΦP1      | -       | 7.30  |
| S        | 6.15TYP |       |
| H1       | 5.44TYP |       |
| b3       | 2.80    | 3.20  |



## MUR3060PT

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